

1. Product profile

1.1 General description

A 300 W LDMOS RF power transistor for broadcast transmitter applications and industrial applications. The transistor can deliver 300 W broadband over the full UHF band from 470 MHz to 860 MHz. The excellent ruggedness and broadband performance of this device makes it ideal for digital transmitter applications.

Table 1. Typical performance

RF performance at $V_{DS} = 42$ V in a common-source 860 MHz narrowband test circuit.

Mode of operation	f (MHz)	P_L (W)	$P_{L(PEP)}$ (W)	$P_{L(AV)}$ (W)	G_p (dB)	η_D (%)	IMD3 (dBc)
CW, class AB	860	300	-	-	21	60	-
2-Tone, class AB	$f_1 = 860$; $f_2 = 860.1$	-	300	-	21	46	-35
PAL BG	860 (ch69)	300 (peak sync.) [1]	-	-	21	45	-
DVB-T (8k OFDM)	858	-	-	75	21	32	-32 [2]

[1] Black video signal, sync expansion: input sync = 33 %; output sync \geq 27 %.

[2] Measured [dBc] with delta marker at 4.3 MHz from center frequency.

CAUTION



This device is sensitive to ElectroStatic Discharge (ESD). Therefore care should be taken during transport and handling.

1.2 Features

- 2-Tone performance at 860 MHz, a drain-source voltage V_{DS} of 42 V and a quiescent drain current $I_{Dq} = 1.4$ A:
 - ◆ Peak envelope power load power = 300 W
 - ◆ Power gain = 21 dB
 - ◆ Drain efficiency = 46 %
 - ◆ Third order intermodulation distortion = -35 dBc
- DVB performance at 858 MHz, a drain-source voltage V_{DS} of 42 V and a quiescent drain current $I_{Dq} = 1.4$ A:
 - ◆ Average output power = 75 W
 - ◆ Power gain = 21 dB
 - ◆ Drain efficiency = 32 %
 - ◆ Third order intermodulation distortion = -32 dBc (4.3 MHz from center frequency)

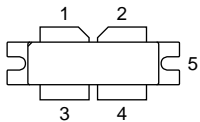
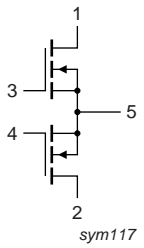
- Integrated ESD protection
- Advanced flange material for optimum thermal behavior and reliability
- Excellent ruggedness
- High power gain
- High efficiency
- Designed for broadband operation (470 MHz to 860 MHz)
- Excellent reliability
- Internal input and output matching for high gain and optimum broadband operation
- Easy power control
- Compliant to Directive 2002/95/EC, regarding Restriction of Hazardous Substances (RoHS)

1.3 Applications

- Communication transmitter applications in the UHF band
- Industrial applications in the UHF band

2. Pinning information

Table 2. Pinning

Pin	Description	Simplified outline	Graphic symbol
1	drain1		
2	drain2		
3	gate1		
4	gate2		
5	source [1]		

[1] Connected to flange.

3. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
BLF878	-	flanged LDMOST ceramic package; 2 mounting holes; 4 leads	SOT979A

4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{DS}	drain-source voltage		-	89	V
V_{GS}	gate-source voltage		-0.5	+11	V
T_{stg}	storage temperature		-65	+150	°C
T_j	junction temperature		-	200	°C

5. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Typ	Unit
$R_{th(j-c)}$	thermal resistance from junction to case	$T_{case} = 80\text{ °C}$; $P_{L(AV)} = 150\text{ W}$	[1]	0.23 K/W
$R_{th(c-h)}$	thermal resistance from case to heatsink		[2]	0.15 K/W

[1] $R_{th(j-c)}$ is measured under RF conditions.

[2] $R_{th(c-h)}$ is dependent on the applied thermal compound and clamping/mounting of the device.

6. Characteristics

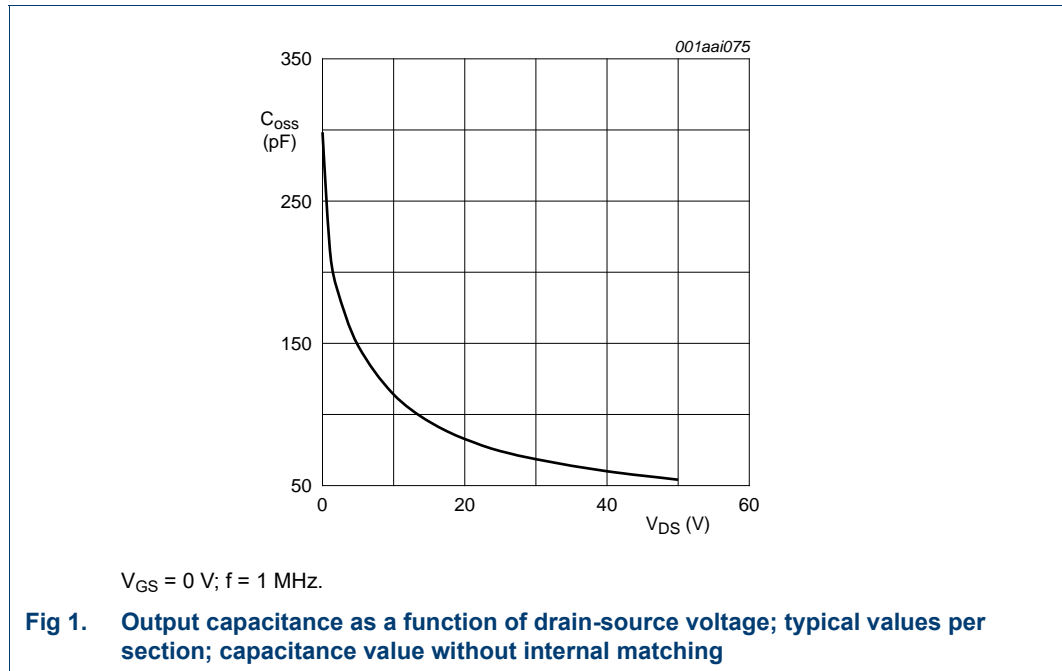
Table 6. Characteristics

$T_j = 25\text{ °C}$ unless otherwise specified.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$V_{(BR)DSS}$	drain-source breakdown voltage	$V_{GS} = 0\text{ V}$; $I_D = 2.25\text{ mA}$	[1]	89	-	105.5 V
$V_{GS(th)}$	gate-source threshold voltage	$V_{DS} = 10\text{ V}$; $I_D = 225\text{ mA}$	[1]	1.4	1.9	2.4 V
I_{DSS}	drain leakage current	$V_{GS} = 0\text{ V}$; $V_{DS} = 42\text{ V}$	-	-	1.4	μA
I_{DSX}	drain cut-off current	$V_{GS} = V_{GSth} + 3.75\text{ V}$; $V_{DS} = 10\text{ V}$	35	39	-	A
I_{GSS}	gate leakage current	$V_{GS} = 11\text{ V}$; $V_{DS} = 0\text{ V}$	-	-	140	nA
g_{fs}	forward transconductance	$V_{DS} = 10\text{ V}$; $I_D = 11.2\text{ A}$	[1]	-	15.5	S
$R_{DS(on)}$	drain-source on-state resistance	$V_{GS} = V_{GSth} + 3.75\text{ V}$; $I_D = 7.6\text{ A}$	[1]	-	110	mΩ
C_{iss}	input capacitance	$V_{GS} = 0\text{ V}$; $V_{DS} = 40\text{ V}$; $f = 1\text{ MHz}$	[2]	-	190	pF
C_{oss}	output capacitance	$V_{GS} = 0\text{ V}$; $V_{DS} = 40\text{ V}$; $f = 1\text{ MHz}$	[2]	-	60	pF
C_{rss}	reverse transfer capacitance	$V_{GS} = 0\text{ V}$; $V_{DS} = 40\text{ V}$; $f = 1\text{ MHz}$	[2]	-	2	pF

[1] I_D is the drain current.

[2] Capacitance values without internal matching.



7. Application information

Table 7. RF performance in a common-source narrowband 860 MHz test circuit
 $T_{case} = 25\text{ °C}$ unless otherwise specified.

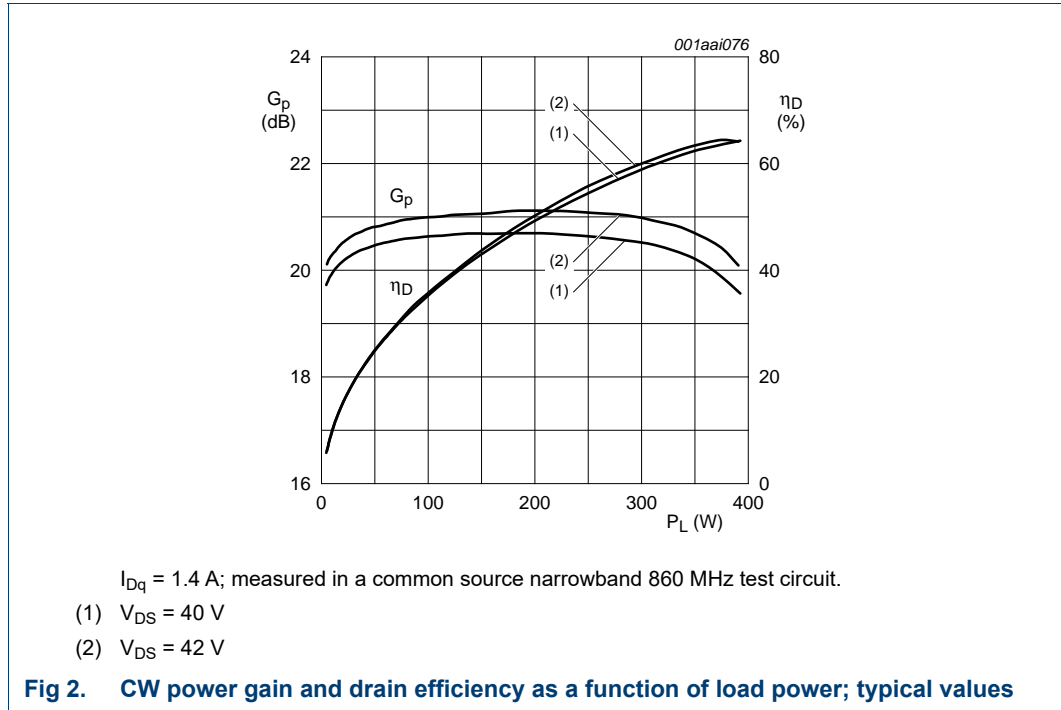
Mode of operation	f (MHz)	V_{DS} (V)	I_{Dq} (A)	$P_{L(PEP)}$ (W)	$P_{L(AV)}$ (W)	G_p (dB)	η_D (%)	IMD3 (dBc)
2-Tone, class AB	$f_1 = 860; f_2 = 860.1$	40	1.4 ^[1]	300	-	> 18	> 42	< -31
DVB-T (8k OFDM)	858	40	1.4 ^[1]	-	75	> 18	> 29	< -29 ^[2]

[1] $I_{Dq} = 1.4\text{ A}$ for total device.

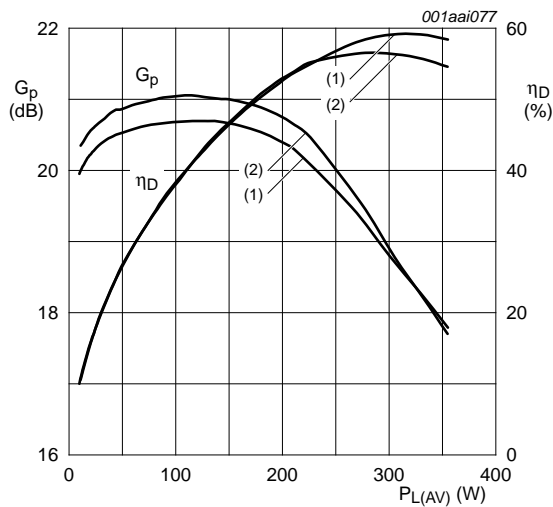
[2] Measured [dBc] with delta marker at 4.3 MHz from center frequency.

7.1 Narrowband RF figures

7.1.1 CW



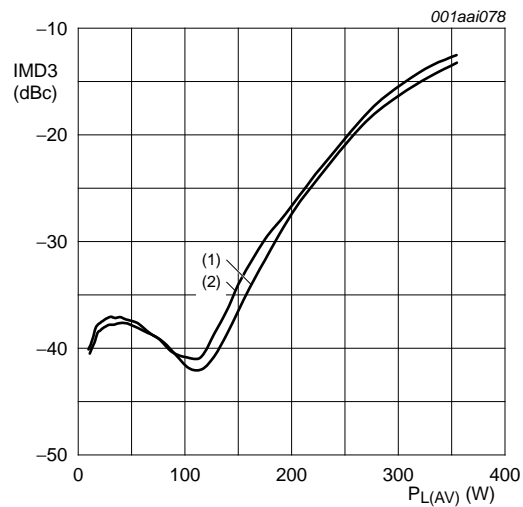
7.1.2 2-Tone



$I_{Dq} = 1.4 \text{ A}$; measured in a common source narrowband 860 MHz test circuit.

- (1) $V_{DS} = 40 \text{ V}$
- (2) $V_{DS} = 42 \text{ V}$

Fig 3. 2-Tone power gain and drain efficiency as functions of average load power; typical values

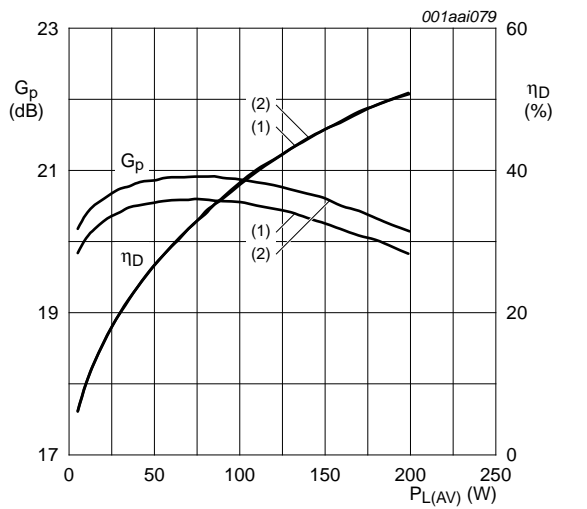


$I_{Dq} = 1.4 \text{ A}$; measured in a common source narrowband 860 MHz test circuit.

- (1) $V_{DS} = 40 \text{ V}$
- (2) $V_{DS} = 42 \text{ V}$

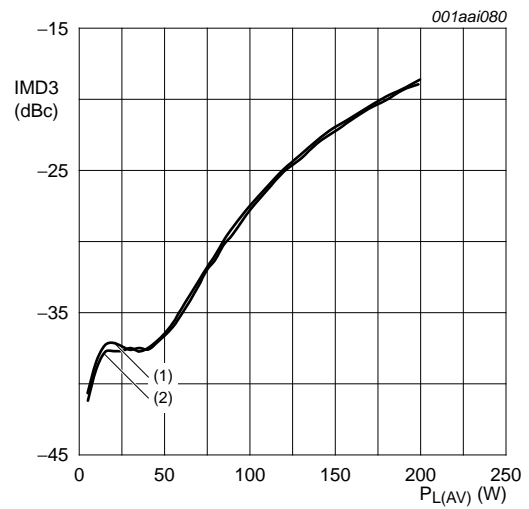
Fig 4. 2-Tone third order intermodulation distortion as a function of average load power; typical values

7.1.3 DVB-T



$I_{Dq} = 1.4 \text{ A}$; measured in a common source narrowband 860 MHz test circuit.
 (1) $V_{DS} = 40 \text{ V}$
 (2) $V_{DS} = 42 \text{ V}$

Fig 5. DVB-T power gain and drain efficiency as functions of average load power; typical values

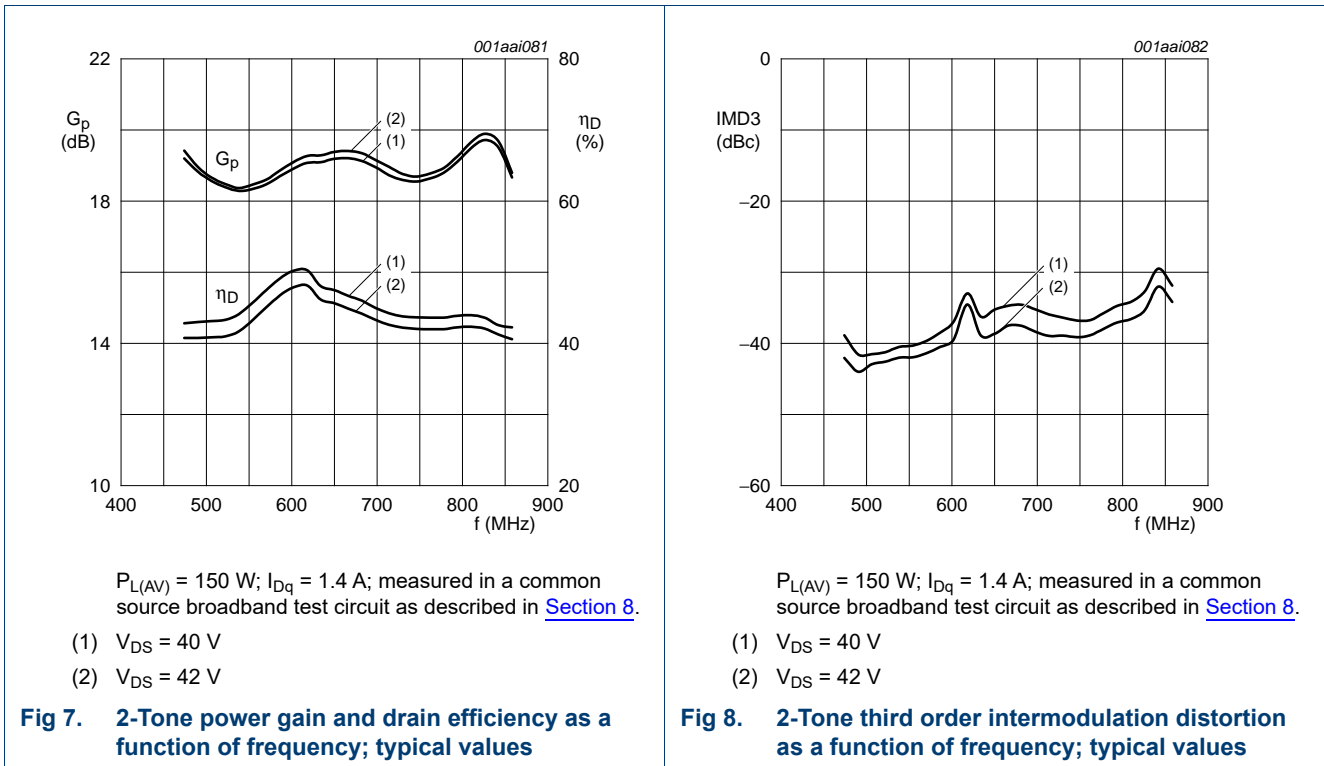


$I_{Dq} = 1.4 \text{ A}$; measured in a common source narrowband 860 MHz test circuit.
 (1) $V_{DS} = 40 \text{ V}$
 (2) $V_{DS} = 42 \text{ V}$

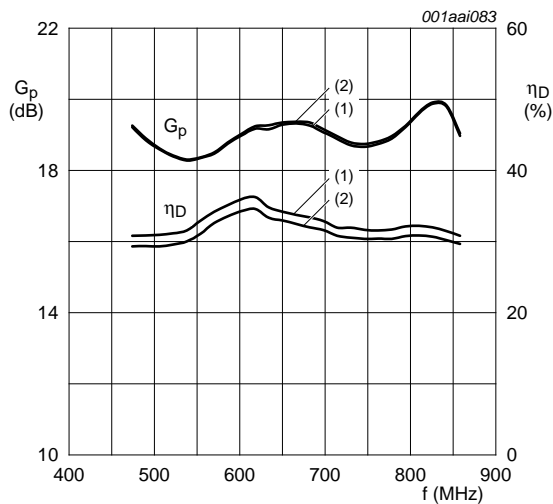
Fig 6. DVB-T third order intermodulation distortion as a function of average load power; typical values

7.2 Broadband RF figures

7.2.1 2-Tone



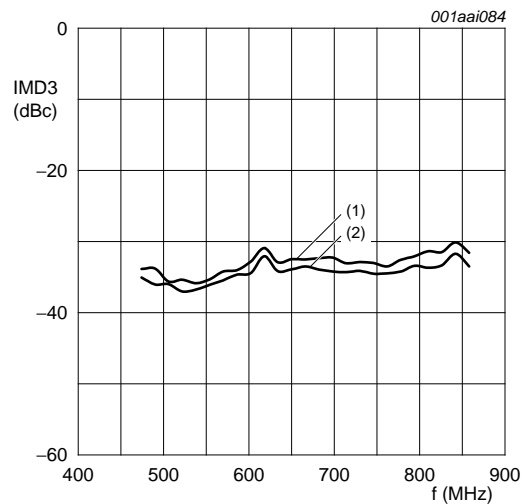
7.2.2 DVB-T



$P_{L(AV)} = 77 \text{ W}$; $I_{Dq} = 1.4 \text{ A}$; measured in a common source broadband test circuit as described in [Section 8](#).

- (1) $V_{DS} = 40 \text{ V}$
- (2) $V_{DS} = 42 \text{ V}$

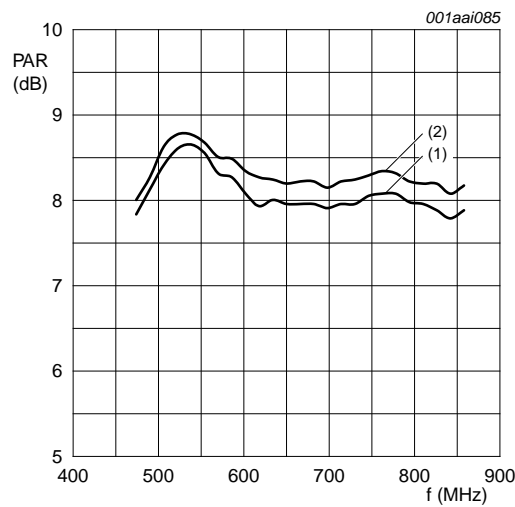
Fig 9. DVB-T power gain and drain efficiency as functions of frequency; typical values



$P_{L(AV)} = 77 \text{ W}$; $I_{Dq} = 1.4 \text{ A}$; measured in a common source broadband test circuit as described in [Section 8](#).

- (1) $V_{DS} = 40 \text{ V}$
- (2) $V_{DS} = 42 \text{ V}$

Fig 10. DVB-T third order intermodulation distortion as a function of frequency; typical values



$P_{L(AV)} = 77 \text{ W}$; $I_{Dq} = 1.4 \text{ A}$; measured in a common source broadband test circuit as described in [Section 8](#).

PAR of input signal = 9.5 dB at 0.01 % probability on CCDF.

- (1) $V_{DS} = 40 \text{ V}$
- (2) $V_{DS} = 42 \text{ V}$

Fig 11. DVB-T PAR at 0.1 % and at 0.01 % probability on the CCDF as function of frequency; typical values

7.3 Ruggedness in class-AB operation

The BLF878 is capable of withstanding a load mismatch corresponding to VSWR = 10 : 1 through all phases under the following conditions: $V_{DS} = 42\text{ V}$; $f = 860\text{ MHz}$ at rated power.

7.4 Impedance information

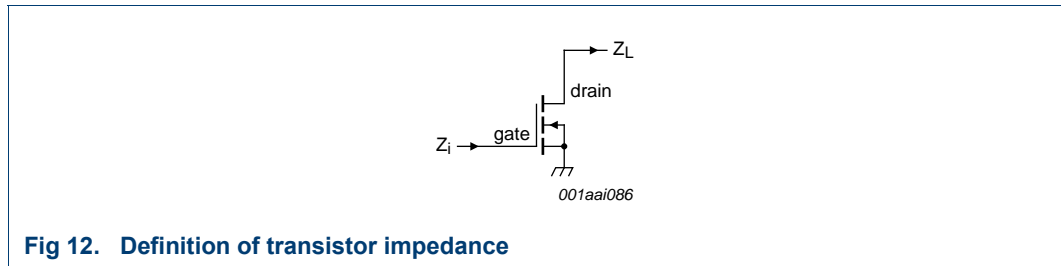


Fig 12. Definition of transistor impedance

Table 8. Typical push-pull impedance

Simulated Z_i and Z_L device impedance; impedance info at $V_{DS} = 42\text{ V}$ and $P_{L(PEP)} = 300\text{ W}$.

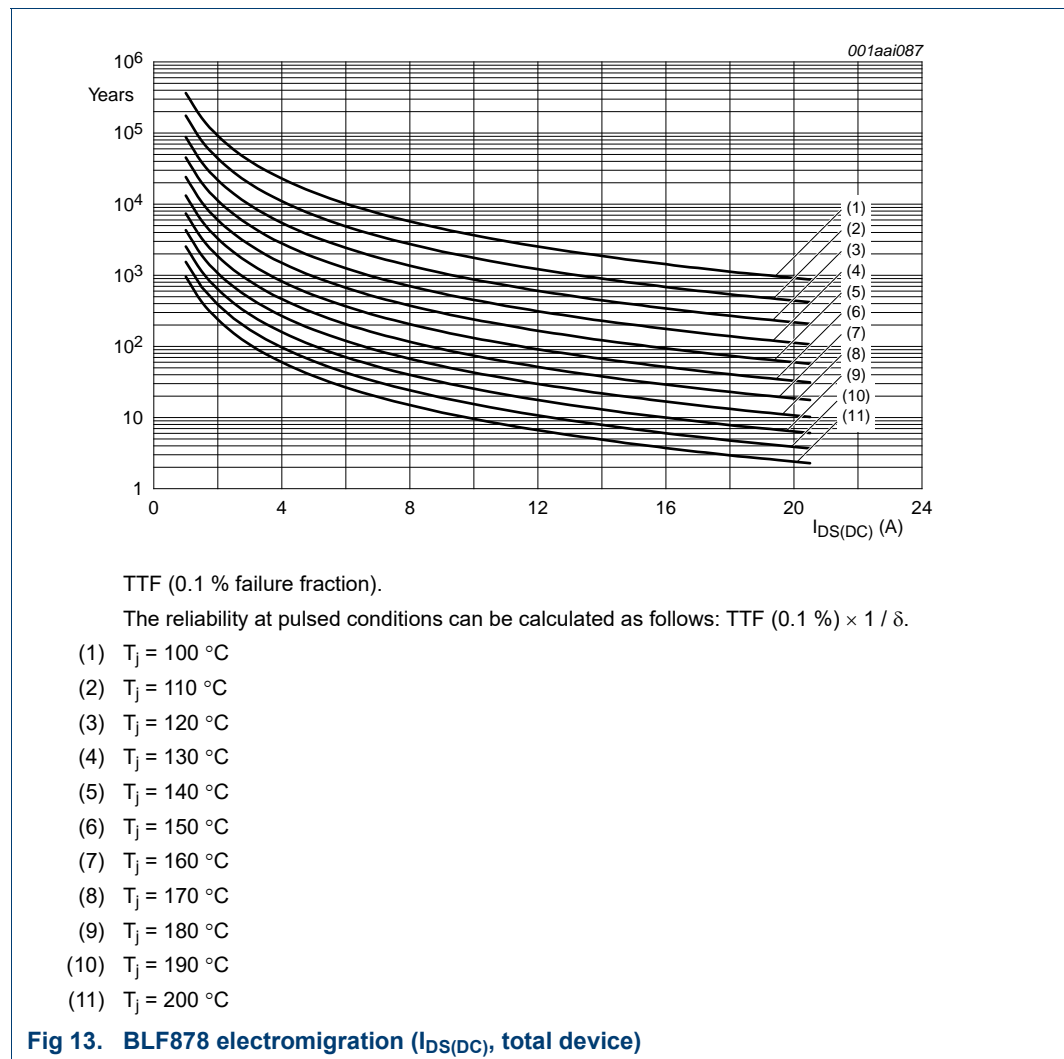
f MHz	Z_i Ω	Z_L Ω
300	0.933 – j1.376	6.431 – j4.296
325	0.959 – j0.986	6.889 – j3.911
350	0.988 – j0.628	7.237 – j3.476
375	1.020 – j0.295	7.475 – j3.017
400	1.057 + j0.017	7.610 – j2.559
425	1.097 + j0.314	7.652 – j2.120
450	1.143 + j0.598	7.614 – j1.713
475	1.194 + j0.871	7.512 – j1.348
500	1.251 + j1.137	7.359 – j1.031
525	1.315 + j1.397	7.168 – j0.762
550	1.388 + j1.652	6.949 – j0.542
575	1.470 + j1.903	6.712 – j0.368
600	1.563 + j2.152	6.465 – j0.237
625	1.668 + j2.398	6.214 – j0.145
650	1.788 + j2.642	5.962 – j0.089
675	1.925 + j2.885	5.714 – j0.064
700	2.082 + j3.125	5.472 – j0.066
725	2.262 + j3.362	5.238 – j0.093
750	2.470 + j3.594	5.012 – j0.141
775	2.711 + j3.816	4.796 – j0.207
800	2.989 + j4.025	4.590 – j0.289
825	3.310 + j4.213	4.394 – j0.385
850	3.680 + j4.369	4.208 – j0.493
875	4.103 + j4.478	4.031 – j0.611
900	4.580 + j4.519	3.864 – j0.737

Table 8. Typical push-pull impedance ...continued

Simulated Z_i and Z_L device impedance; impedance info at $V_{DS} = 42\text{ V}$ and $P_{L(PEP)} = 300\text{ W}$.

f MHz	Z_i Ω	Z_L Ω
925	5.103 + j4.467	3.706 - j0.871
950	5.656 + j4.291	3.556 - j1.011
975	6.205 + j3.963	3.415 - j1.157
1000	6.696 + j3.463	3.281 - j1.308

7.5 Reliability



8. Test information

Table 9. List of components

For test circuit, see [Figure 14](#), [Figure 15](#) and [Figure 16](#).

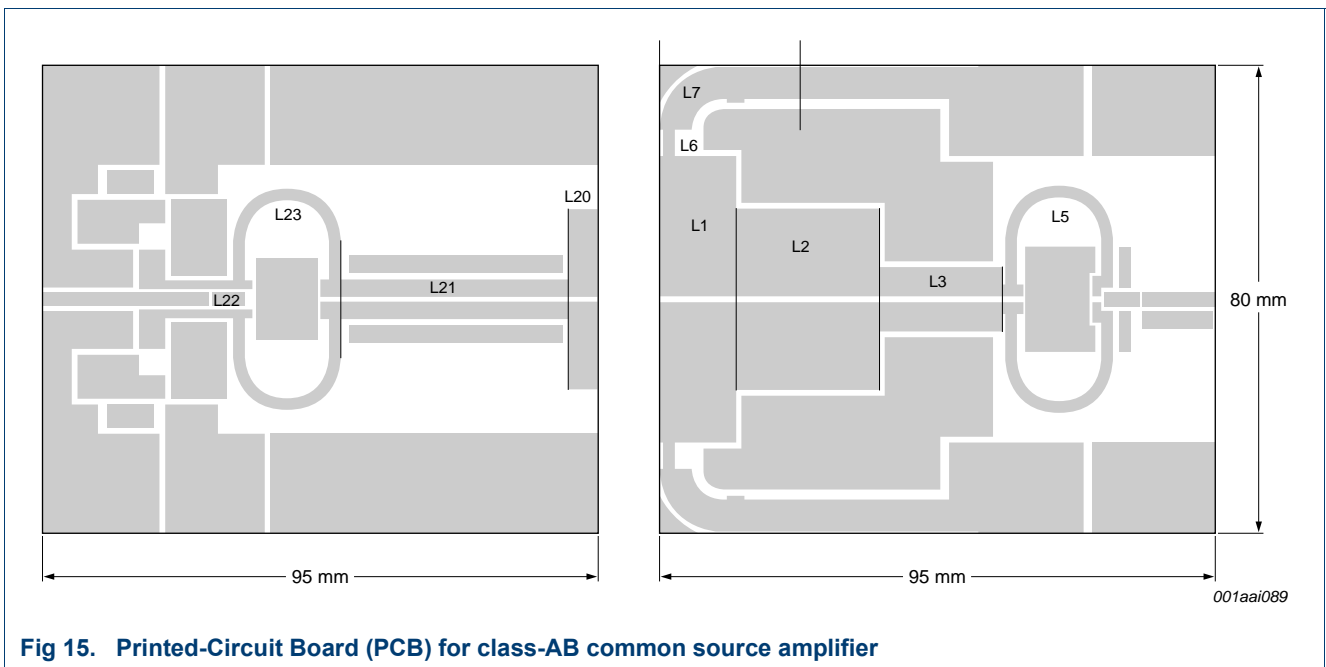
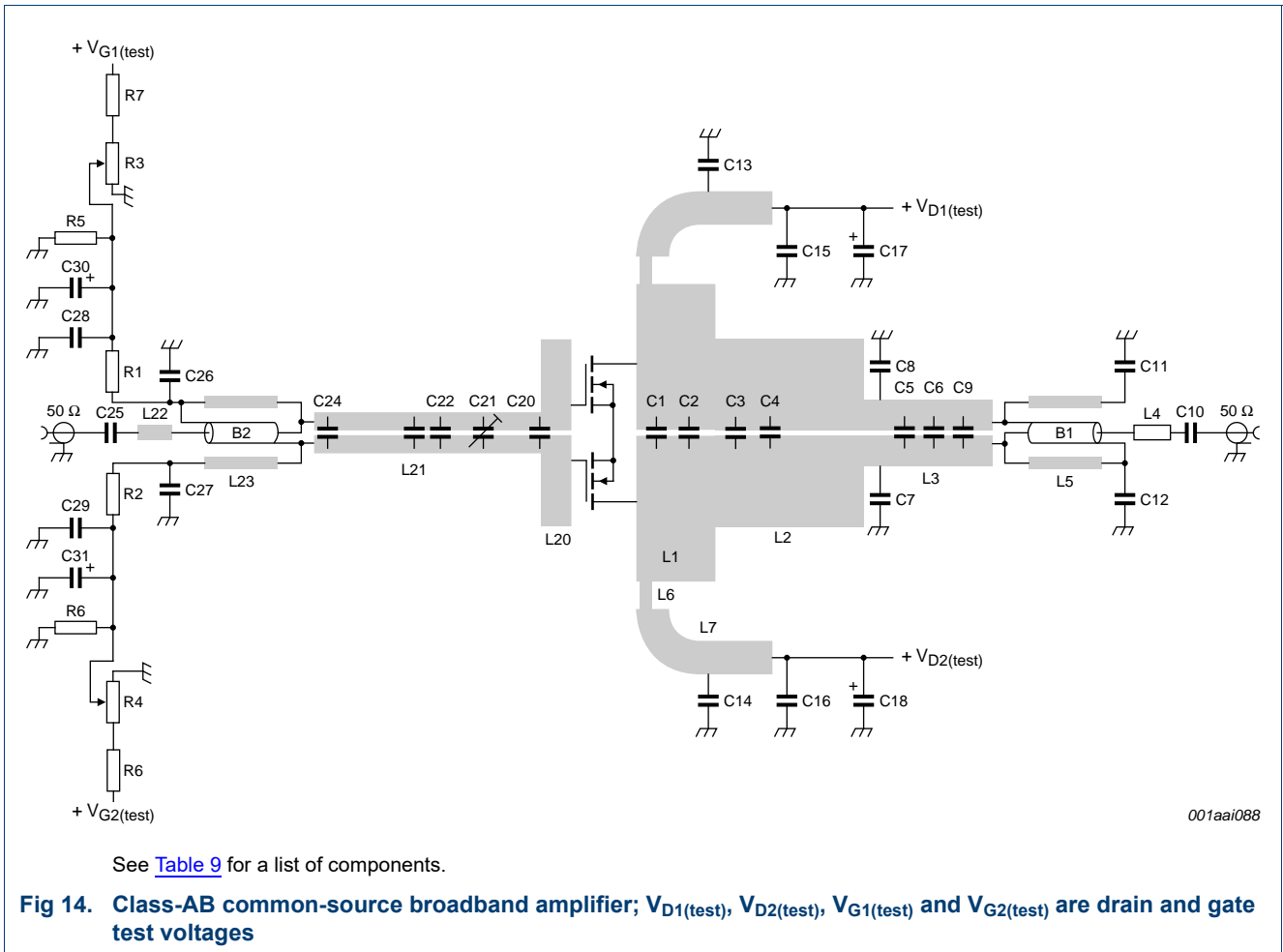
Component	Description	Value	Remarks
B1, B2	semi rigid coax	25 Ω; 43.5 mm	EZ90-25-TP
C1, C2	multilayer ceramic chip capacitor	8.2 pF	[1]
C3, C9	multilayer ceramic chip capacitor	3.9 pF	[2]
C4	multilayer ceramic chip capacitor	2.7 pF	[2]
C5, C7, C8	multilayer ceramic chip capacitor	6.8 pF	[1]
C6	multilayer ceramic chip capacitor	2.2 pF	[2]
C10	multilayer ceramic chip capacitor	47 pF	[2]
C11, C12	multilayer ceramic chip capacitor	100 pF	[1]
C13, C14	multilayer ceramic chip capacitor	100 pF	[2]
C15, C16	multilayer ceramic chip capacitor	10 μF	TDK C570X7R1H106KT000N or capacitor of same quality.
C17, C18	electrolytic capacitor	470 μF; 63 V	
C20	multilayer ceramic chip capacitor	15 pF	[3]
C21	trimmer	0.6 pF to 4.5 pF	Tekelec
C22	multilayer ceramic chip capacitor	11 pF	[3]
C23	multilayer ceramic chip capacitor	3.9 pF	[3]
C24	multilayer ceramic chip capacitor	4.7 pF	[3]
C25, C26, C27	multilayer ceramic chip capacitor	100 pF	[3]
C28, C29	multilayer ceramic chip capacitor	560 pF	[2]
C30, C31	electrolytic capacitor	10 μF	
L1	stripline	-	[4] (W × L) 24 mm × 13 mm
L2	stripline	-	[4] (W × L) 15 mm × 24.5 mm
L3	stripline	-	[4] (W × L) 5 mm × 21 mm
L4	stripline	-	[4] (W × L) 2.4 mm × 6 mm
L5, L23	stripline	-	[4] (W × L) 2 mm × 43.5 mm
L6	stripline	-	[4] (W × L) 2 mm × 4.5 mm
L7	stripline	-	[4] (W × L) 5.5 mm × 24 mm
L20	stripline	-	[4] (W × L) 15 mm × 5 mm
L21	stripline	-	[4] (W × L) 3 mm × 39 mm
L22	stripline	-	[4] (W × L) 2.4 mm × 5.7 mm
R1, R2	resistor	5.6 Ω	long wires
R3, R4	potentiometer	10 kΩ	
R5, R6	resistor	10 kΩ	
R7, R8	resistor	1 kΩ	

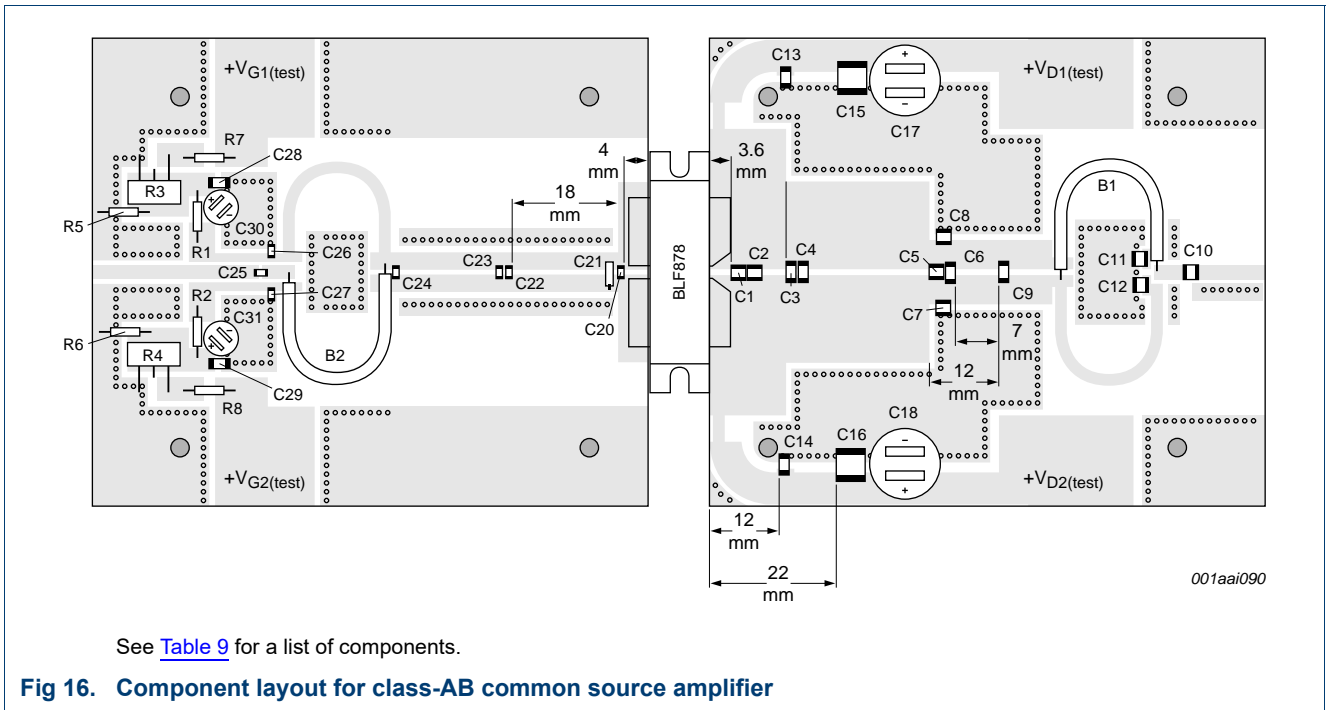
[1] American technical ceramics type 180R or capacitor of same quality.

[2] American technical ceramics type 100B or capacitor of same quality.

[3] American technical ceramics type 100A or capacitor of same quality.

[4] Printed-Circuit Board (PCB): Rogers 5880; $\epsilon_r = 2.2$ F/m; height = 0.79 mm; Cu (top/bottom metallization); thickness copper plating = 35 μm.





9. Package outline

Flanged LDMOST ceramic package; 2 mounting holes; 4 leads

SOT979A

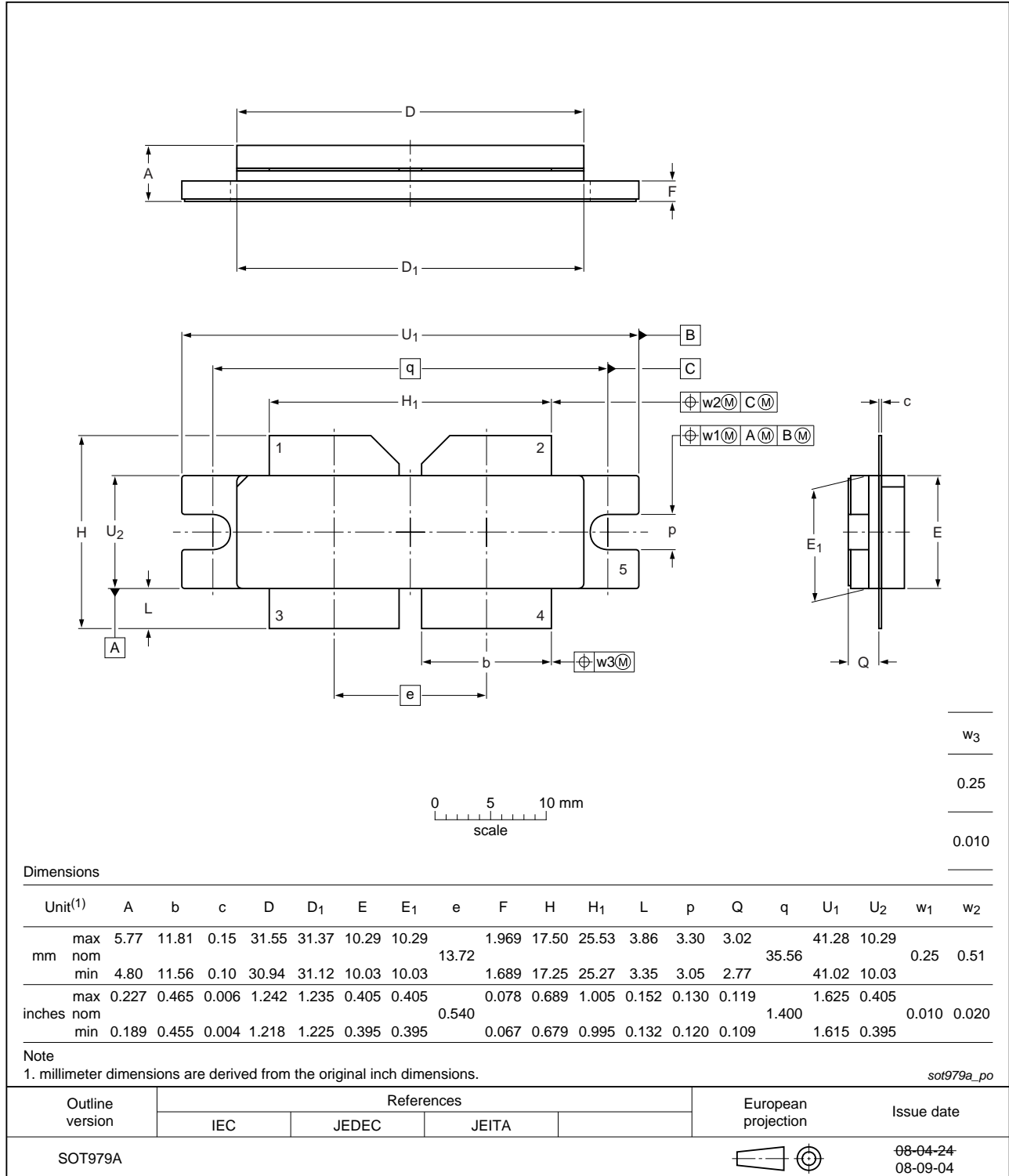


Fig 17. Package outline SOT979A

10. Abbreviations

Table 10. Abbreviations

Acronym	Description
CW	Continuous Wave
CCDF	Complementary Cumulative Distribution Function
DVB	Digital Video Broadcast
DVB-T	Digital Video Broadcast - Terrestrial
ESD	ElectroStatic Discharge
IMD3	Third order InterModulation Distortion
LDMOS	Laterally Diffused Metal-Oxide Semiconductor
LDMOST	Laterally Diffused Metal-Oxide Semiconductor Transistor
OFDM	Orthogonal Frequency Division Multiplexing
PAL	Phase Alternating Line
PAR	Peak-to-Average power Ratio
PEP	Peak Envelope Power
RF	Radio Frequency
TTF	Time To Failure
UHF	Ultra High Frequency
VSWR	Voltage Standing-Wave Ratio

11. Revision history

Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BLF878#3	20150901	Product data sheet	-	BLF878_2
Modifications:	<ul style="list-style-type: none"> The format of this document has been redesigned to comply with the new identity guidelines of Ampleon. Legal texts have been adapted to the new company name where appropriate. 			
BLF878_2	20090615	Product data sheet	-	BLF878_1
BLF878_1	20081215	Preliminary data sheet	-	-

12. Legal information

12.1 Data sheet status

Document status ^{[1][2]}	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <http://www.ampleon.com>.

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14. Contents

1	Product profile	1
1.1	General description	1
1.2	Features	1
1.3	Applications	2
2	Pinning information	2
3	Ordering information	2
4	Limiting values	3
5	Thermal characteristics	3
6	Characteristics	3
7	Application information	4
7.1	Narrowband RF figures	5
7.1.1	CW	5
7.1.2	2-Tone	6
7.1.3	DVB-T	7
7.2	Broadband RF figures	8
7.2.1	2-Tone	8
7.2.2	DVB-T	9
7.3	Ruggedness in class-AB operation	10
7.4	Impedance information	10
7.5	Reliability	11
8	Test information	12
9	Package outline	15
10	Abbreviations	16
11	Revision history	16
12	Legal information	17
12.1	Data sheet status	17
12.2	Definitions	17
12.3	Disclaimers	17
12.4	Trademarks	18
13	Contact information	18
14	Contents	19

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